

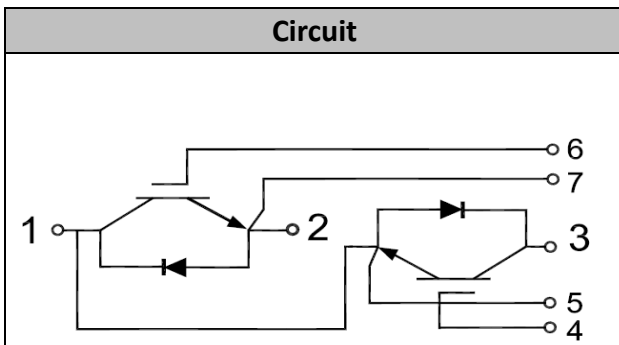


IGBT Modules

V _{CES}	1200V
I _C	150A

Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- UPS (Uninterruptible Power Supplies)
- Soft switching welding machine



Features

- Low V_{ce(sat)} with Trench technology
- V_{ce(sat)} with positive temperature coefficient
- High short circuit capability(10us)
- Including ultra fast & soft recovery anti-parallel FWD
- Low inductance
- Maximum junction temperature 175°C

● IGBT

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Collector-Emitter Voltage	V _{CES}	V _{GE} =0V, I _C =1mA, T _{vj} =25°C	1200	V
Continuous Collector Current	I _C	T _c =100°C	150	A
Repetitive Peak Collector Current	I _{CRM}	t _p =1ms	300	A
Gate-Emitter Voltage	V _{GES}	T _{vj} =25°C	±20	V
Total Power Dissipation	P _{tot}	T _c =25°C T _{vjmax} =175°C	968	W



MG150HF12TLC1 RoHS COMPLIANT

Characteristic values

Parameter	Symbol	Conditions	Value			Unit	
			Min.	Typ.	Max.		
Gate-emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=5mA, T_{vj}=25^{\circ}C$	5.0	5.7	6.5	V	
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25^{\circ}C$			1.0	mA	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=150A, V_{GE}=15V, T_{vj}=25^{\circ}C$		1.90	2.20	V	
		$I_C=150A, V_{GE}=15V, T_{vj}=125^{\circ}C$		2.20			
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25^{\circ}C$		9.8		nF	
Reverse Transfer Capacitance	C_{res}			0.48		nF	
Internal Gate Resistance	R_{gint}			2.5		Ω	
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25^{\circ}C$			400	nA	
Turn-on Delay Time	$t_{d(on)}$	$I_C=150A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_G=5.1\Omega$ $T_{vj}=25^{\circ}C$		185		ns	
Rise Time	t_r			55		ns	
Turn-off Delay Time	$t_{d(off)}$			360		ns	
Fall Time	t_f			115		ns	
Energy Dissipation During Turn-on Time	E_{on}			15.4		mJ	
Energy Dissipation During Turn-off Time	E_{off}			11.6		mJ	
Turn-on Delay Time	$t_{d(on)}$		$I_C=150A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_G=5.1\Omega$ $T_{vj}=125^{\circ}C$		200		ns
Rise Time	t_r				60		ns
Turn-off Delay Time	$t_{d(off)}$				420		ns
Fall Time	t_f				120		ns
Energy Dissipation During Turn-on Time	E_{on}			23.2		mJ	
Energy Dissipation During Turn-off Time	E_{off}			17.0		mJ	
SC Data	I_{sc}	$T_p \leq 10\mu s, V_{GE}=15V,$ $T_{vj}=150^{\circ}C, V_{cc}=600V,$ $V_{CEM} \leq 1200V$			500		A



● Diode

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25^{\circ}C$	1200	V
Continuous DC Forward Current	I_F		150	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1ms$	300	A

Characteristic values

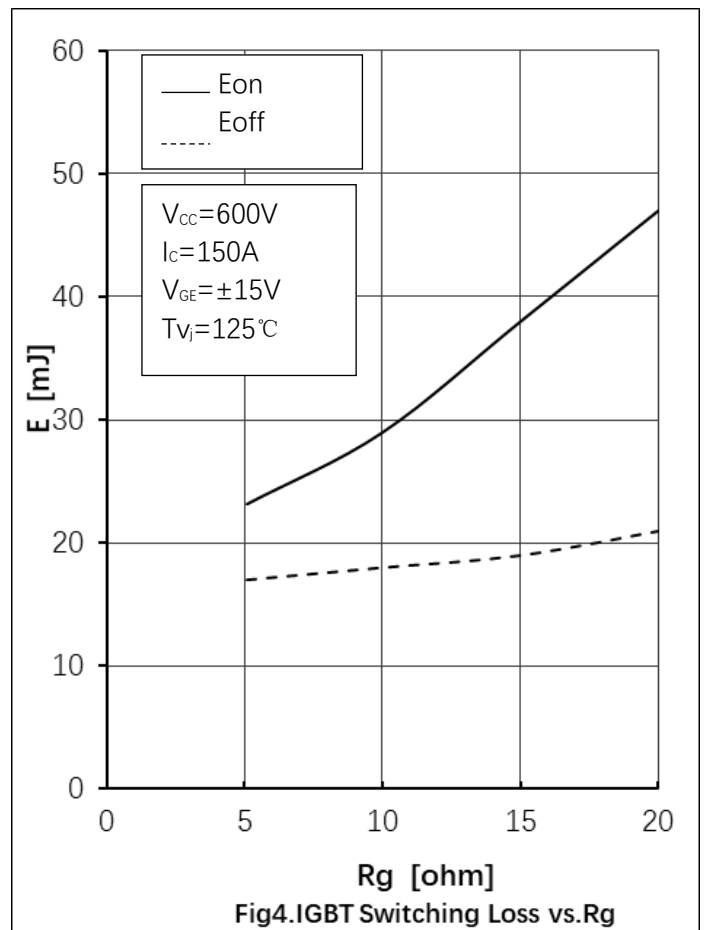
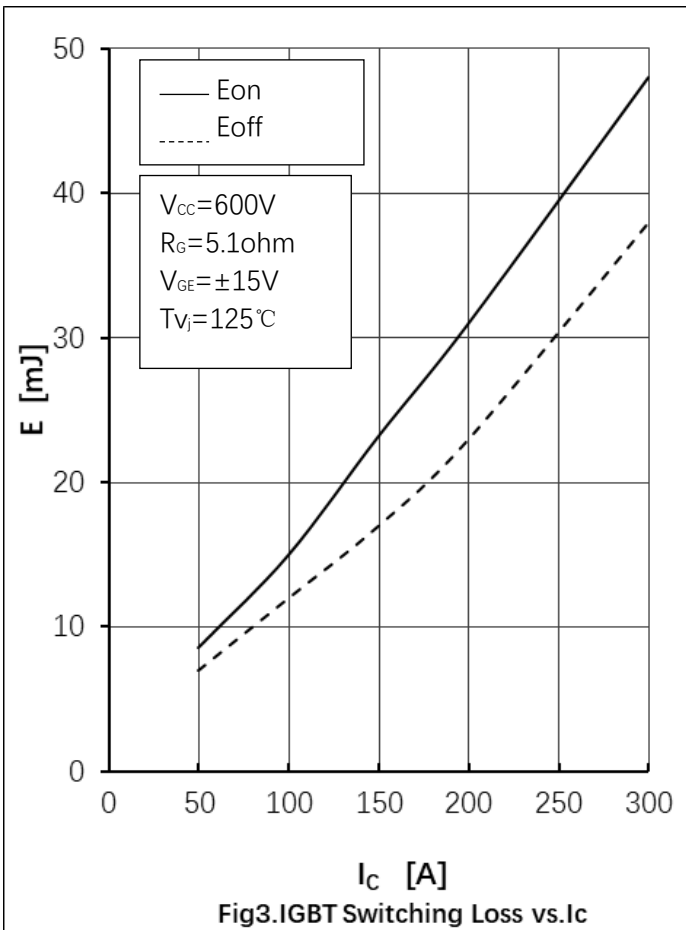
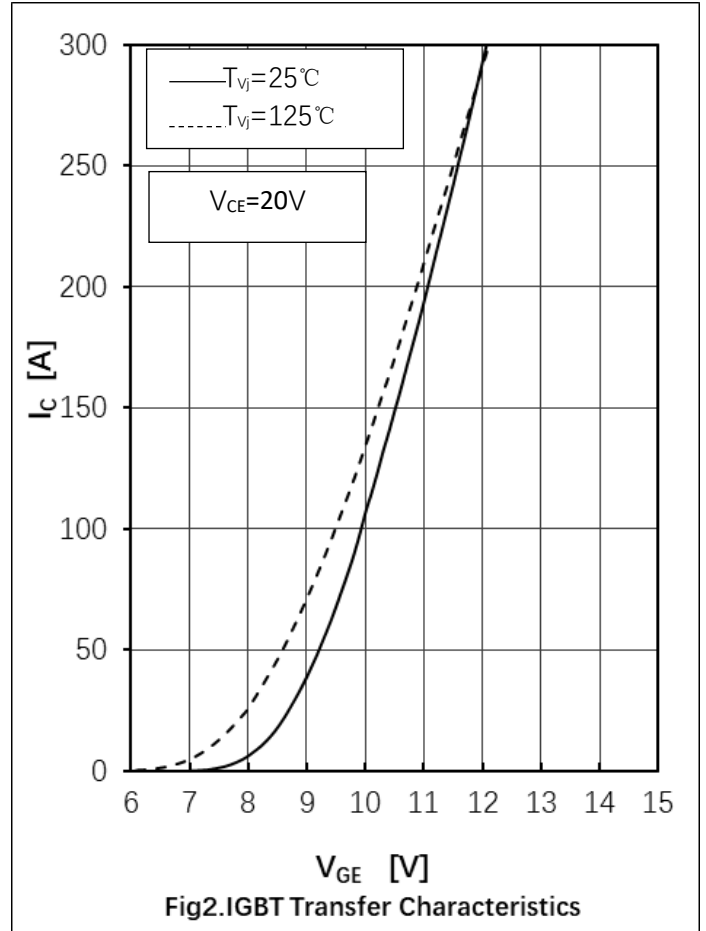
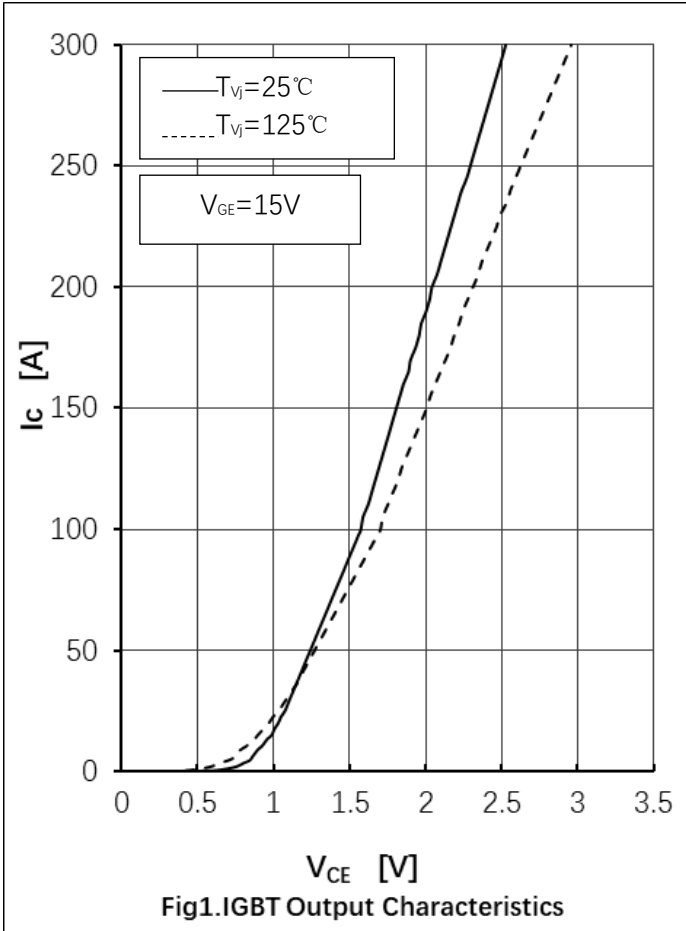
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F=150A, T_{vj}=25^{\circ}C$		2.0		V
		$I_F=150A, T_{vj}=125^{\circ}C$		2.0		
Recovered Charge	Q_{rr}	$I_F=150A$		13.4		μC
Peak Reverse Recovery Current	I_{rr}	$V_R=600V$ $-di_F/dt=2200A/\mu s$		143		A
Reverse Recovery Energy	E_{rec}	$T_{vj}=25^{\circ}C$		9.1		mJ
Recovered Charge	Q_{rr}	$I_F=150A$ $V_R=600V$ $-di_F/dt=2200A/\mu s$		26.1		μC
Peak Reverse Recovery Current	I_{rr}			178		A
Reverse Recovery Energy	E_{rec}		$T_{vj}=125^{\circ}C$		15.4	

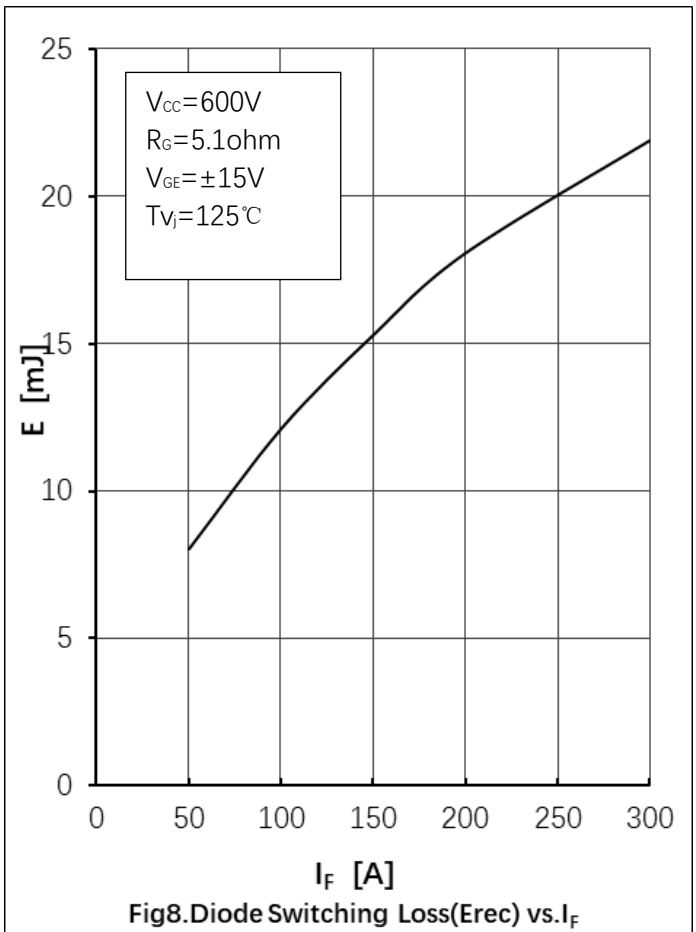
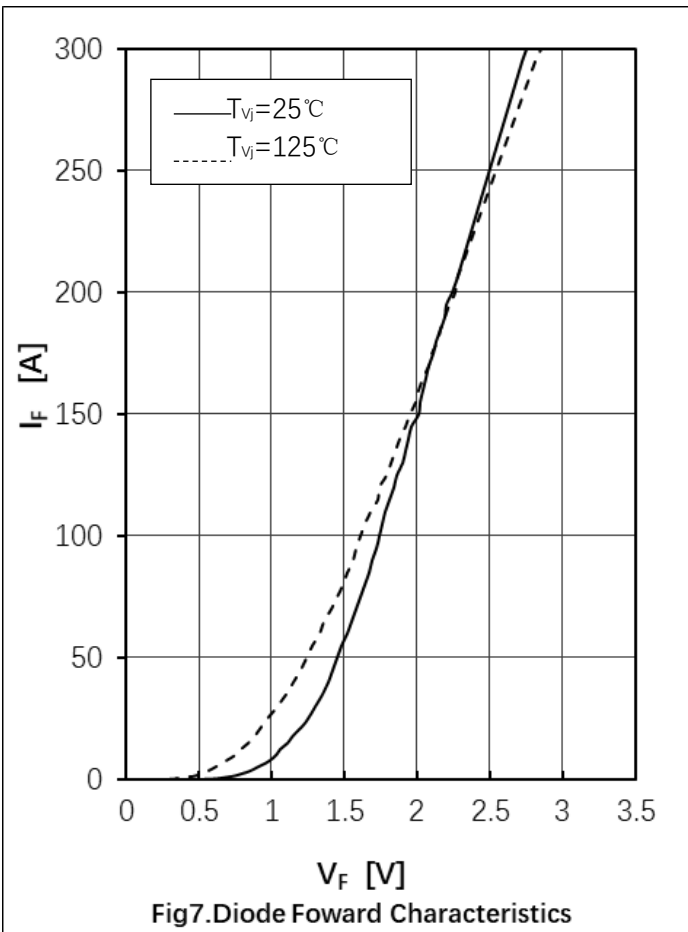
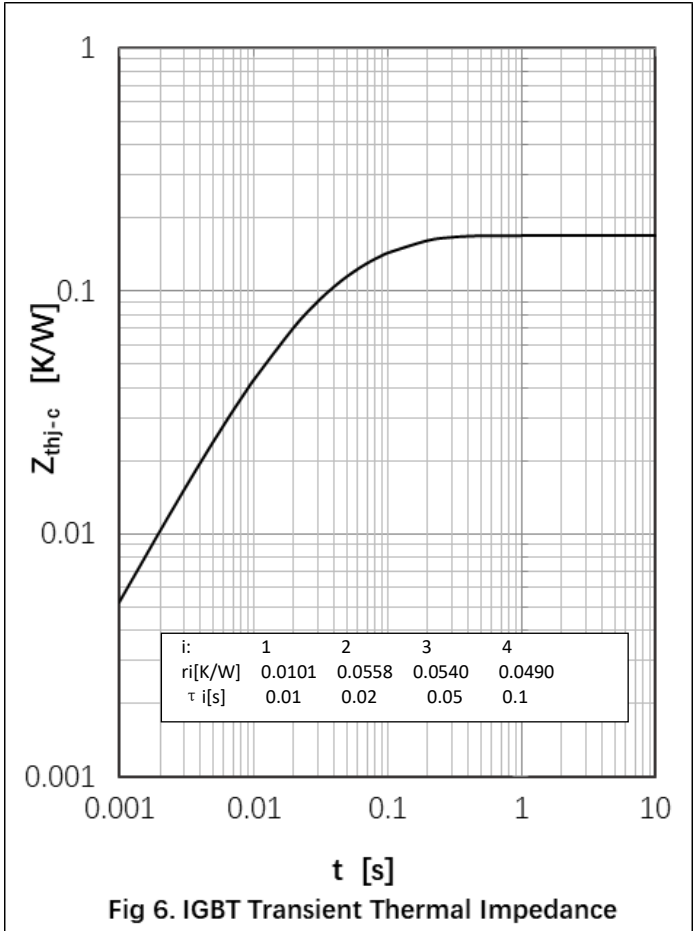
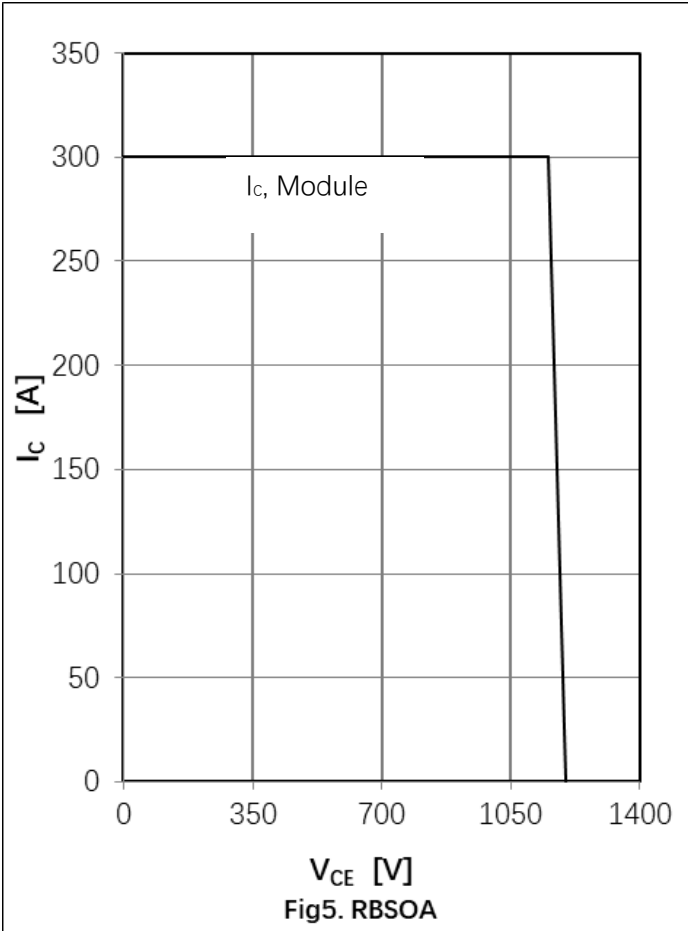


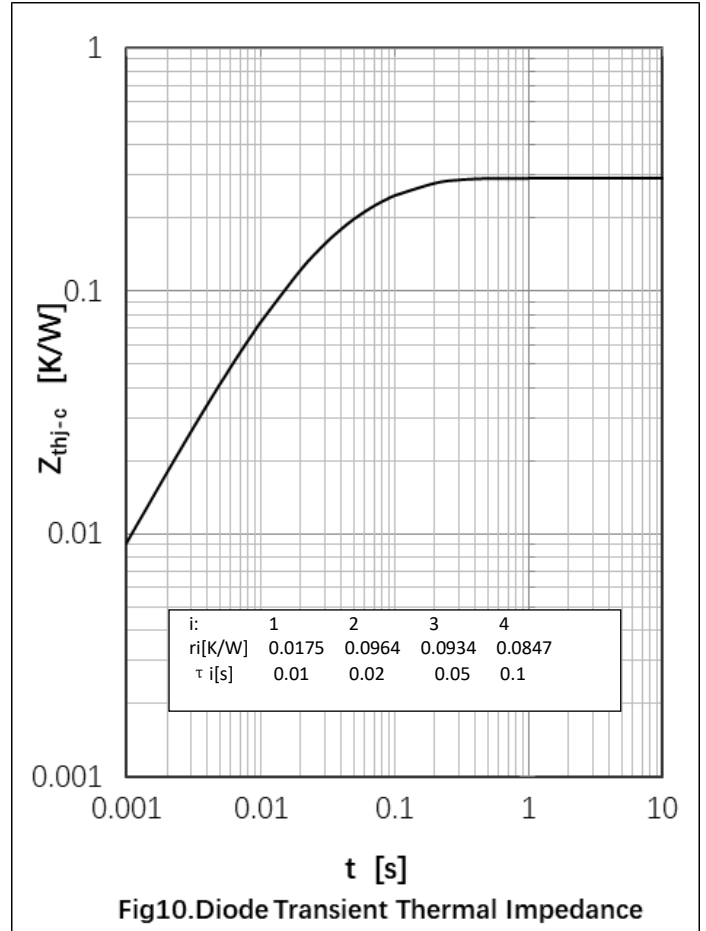
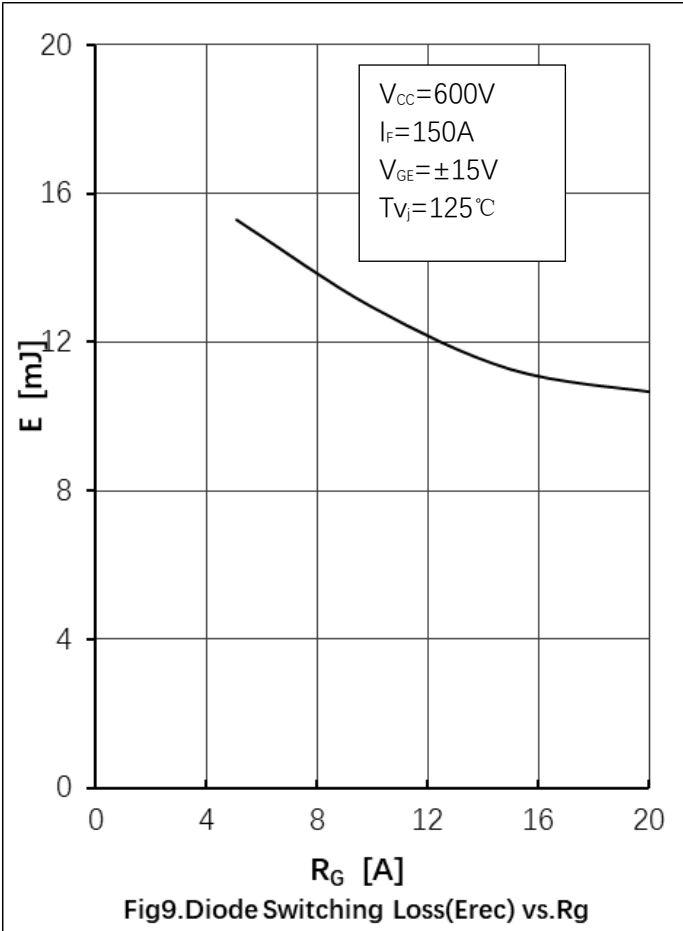
● Module Characteristics

T_c=25°C unless otherwise specified

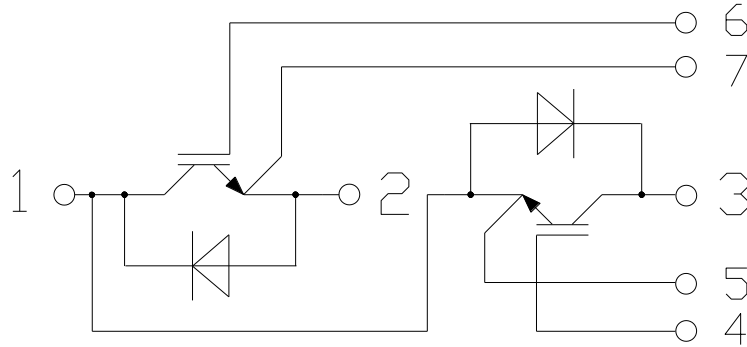
Parameter	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Isolation voltage	V _{isol}	t=1min,f=50Hz	2500			V
Maximum Junction Temperature	T _{jmax}				175	°C
Operating Junction Temperature	T _{vj op}		-40		150	°C
Storage Temperature	T _{stg}		-40		125	°C
Thermal Resistance Junction-to Case	R _{θJC}	per IGBT			0.155	K/W
		per Diode			0.29	
Thermal Resistance Case-to Sink	R _{θCS}	Conductive grease applied		0.05		K/W
Module Electrodes Torque	M _t	Recommended(M5)	2.5		5.0	N·m
Module-to-Sink Torque	M _s	Recommended(M6)	3.0		5.0	N·m
Weight of Module	G			150		g







● **Circuit Diagram**



● **Package Outline Information**

Dimensions in Millimeters

